

Squaraine based Solution Processed Inverted Bulk Heterojunction Solar Cells Processed in Air

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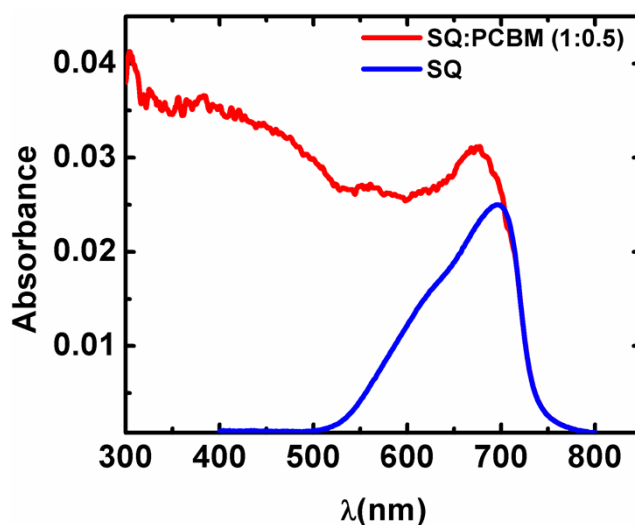


Fig. S1 UV-Vis absorption of SQ:PCBM (of blend ratio 1:0.5) thin films of 100 nm thickness and that of pristine Squaraine of 100 nm thickness

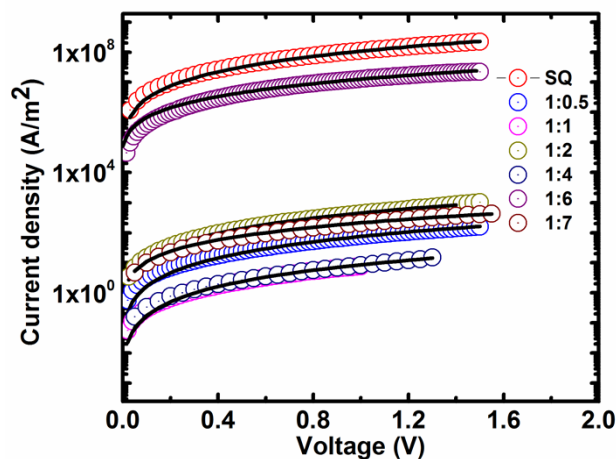


Fig.S2 Dark J-V characteristics of hole only, ITO/PEDOT:PSS/SQN:PCBM/Au devices of different SQN:PCBM blend ratio. Straight line shows the calculated J-V characteristics using SCLC model

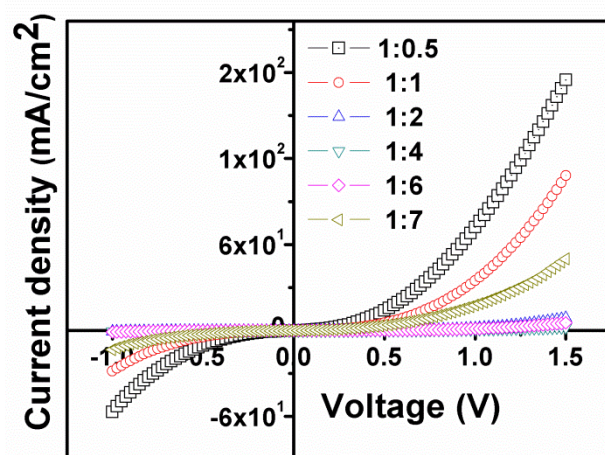


Fig. S3. Dark Current -Voltage characteristics of SQ: PCBM inverted bulk heterojunction solar cell in different donor : acceptor blend ratio

SQ:PCBM blend ratio	Rectification ratio at 1 Volt
1:0.5	1.28
1:1	1.221
1:2	2.617
1:4	1.23
1:6	1.15
1:7	1.325

Table S1. Rectification ratio of the devices with different SQ: PCBM blend ratios